

FMR23N50E

FUJI POWER MOSFET

Super FAP-E³ series

N-CHANNEL SILICON POWER MOSFET

■ Features

Maintains both low power loss and low noise Lower R_{DS}(on) characteristic More controllable switching dv/dt by gate resistance Smaller V_{GS} ringing waveform during switching Narrow band of the gate threshold voltage (3.0±0.5V) High avalanche durability

Applications

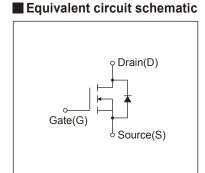
Switching regulators UPS (Uninterruptible Power Supply) DC-DC converters

Maximum Ratings and Characteristics

● Absolute Maximum Ratings at Tc=25°C (unless otherwise specified)

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■ Outline Drawings [mm]



Description	Symbol	Characteristics	Unit	Remarks
Drain Sauras Valtaria	V _{DS}	500	V	
Drain-Source Voltage	V _{DSX}	500	V	V _{GS} = -30V
Continuous Drain Current	ID	±23	A	
Pulsed Drain Current	I _{DP}	±92	A	
Gate-Source Voltage	V _{GS}	±30	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	23	A	Note*1
Non-Repetitive Maximum Avalanche Energy	Eas	767.3	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	15	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	9.3	kV/μs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Maximum Power Dissipation	Pn	3.13	W	Ta=25°C
waximum Power Dissipation	PD	150	VV	Tc=25°C
Operating and Storage	Tch	150	°C	
Temperature range	Tstg	-55 to + 150	°C	
Isolation Voltage	Viso	2	kVrms	t = 60sec, f = 60Hz

● Electrical Characteristics at Tc=25°C (unless otherwise specified)

Description	Symbol	Conditions		min.	typ.	max.	Unit	
Drain-Source Breakdown Voltage	BVDSS	I _D =250μA, V _{GS} =0V		500	-	-	V	
Gate Threshold Voltage	V _{GS} (th)	ID=250µA, VDS=VGS		2.5	3.0	3.5	V	
Zee Oats Walkers Burks Oassat		V _{DS} =500V, V _{GS} =0V	ch=25°C	-	-	25		
Zero Gate Voltage Drain Current	IDSS	V _{DS} =400V, V _{GS} =0V T	ch=125°C	-	-	250	μA	
Gate-Source Leakage Current	Igss	V _{GS} =±30V, V _{DS} =0V		-	10	100	nA	
Drain-Source On-State Resistance	R _{DS} (on)	I _D =11.5A, V _{GS} =10V		-	0.21	0.245	Ω	
Forward Transconductance	g _{fs}	I _D =11.5A, V _{DS} =25V		14	28	-	S	
Input Capacitance	Ciss	V _{DS} =25V	-	3500	5250	pF		
Output Capacitance	Coss	V _{GS} =0V	-	330	495			
Reverse Transfer Capacitance	Crss	f=1MHz	-	24	36			
Turn-On Time	td(on) V _{cc} =300V			-	24	36	ns	
Turn-On Time	tr	V _{GS} =10V I _D =11.5A		-	13	19.5		
Turn-Off Time	td(off)			-	150	225		
Turn-On Time	tf	R _{GS} =5.6Ω		-	20	30		
	Qth	Vcc=250V In=23A Vcs=10V		-	11	16.5	nC	
Total Gate Charge	Q _G			-	93	139.5		
Gate-Source Charge	Q _{GS}			-	24	36		
Gate-Drain Charge	Q _{GD}	V 03 – 10 V	-	30	45			
Avalanche Capability	lav	L=1.16mH, Tch=25°C		23	-	-	Α	
Diode Forward On-Voltage	V _{SD}	I _F =23A, V _{GS} =0V, T _{ch} =25°C		-	0.90	1.35	V	
Reverse Recovery Time	trr	I _F =23A, V _{GS} =0V		-	0.5	-	μs	
Reverse Recovery Charge	Qrr	-di/dt=100A/µs, Tch=25°C		-	8	-	μC	

Thermal Characteristics

Description	Symbol	Test Conditions	min.	typ.	max.	Unit
Thermal resistance	Rth (ch-c)	Channel to case			0.83	°C/W
	Rth (ch-a)	Channel to ambient			40.0	°C/W

Note *1 : Tch≤150°C

Note *2 : Stating Tch=25°C, Ias=10A, L=14.1mH, Vcc=50V, Re=50Ω

Eas limited by maximum channel temperature and avalanche current.

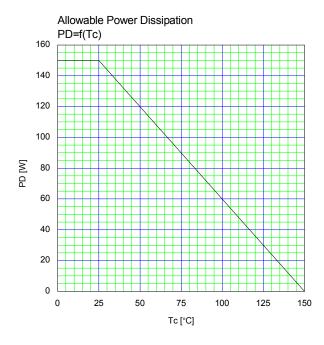
See to 'Avalanche Energy' graph.

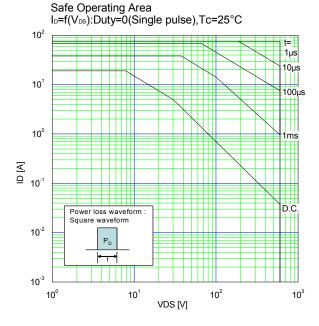
Note $^{\star}3$: Repetitive rating : Pulse width limited by maximum channel temperature

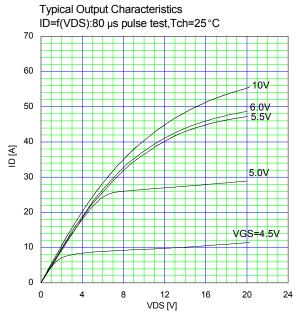
See to the 'Transient Themal impeadance' graph.

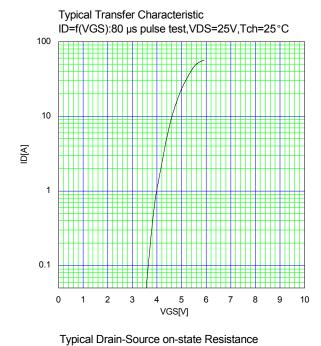
Note *4 : I₅≤-I₀, -di/dt=100A/μ₅, Vcc≤BV₀ss, Tch≤150°C.

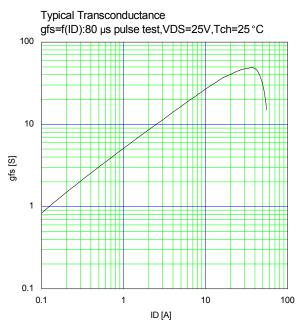
Note *5 : I₅≤-I₀, dv/dt=5.0kV/μ₅, Vcc≤BV₀ss, Tch≤150°C.

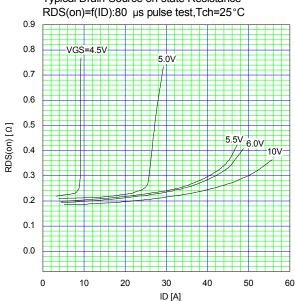


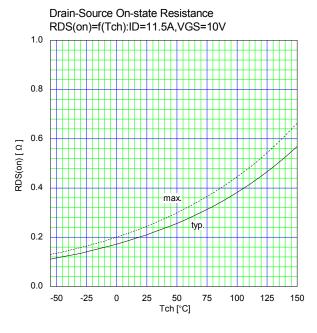


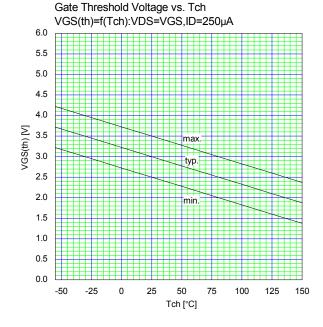


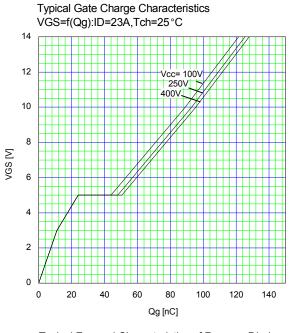


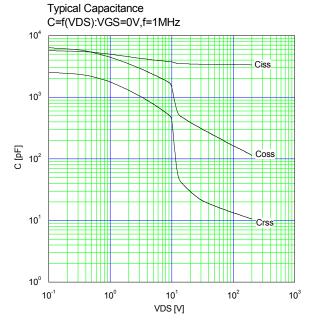


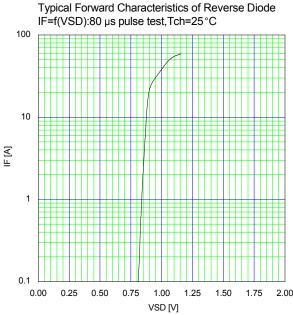


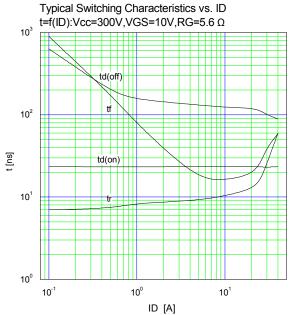




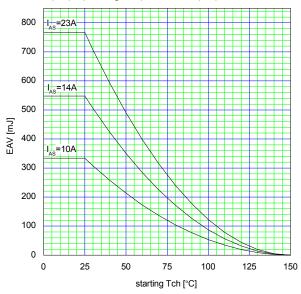


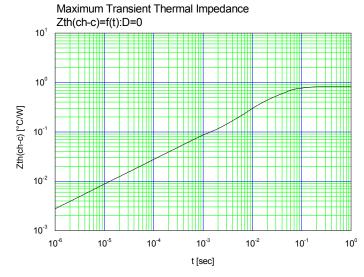






Maximum Avalanche Energy vs. starting Tch E(AV)=f(starting Tch):Vcc=50V,I(AV)<=23A





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